



A Product Line of Diodes Incorporated

ZXT10P12DE6

#### **12V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26**

#### Features

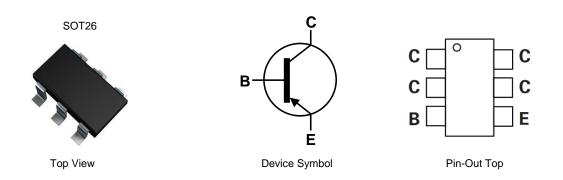
- BV<sub>CEO</sub> > -12V
- I<sub>C</sub> = 3A Continuous Collector Current
- I<sub>CM</sub> = -10A Peak Pulse Current
- R<sub>CE(sat)</sub> = 65mΩ for a Low Equivalent On-Resistance
- Low Saturation Voltage (-100mV max @ 1A)
- h<sub>FE</sub> Characterized up to -10A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.015 grams (Approximate)

### Applications

- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control



#### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P12DE6TA	717	7	8	3,000
ZXT10P12DE6TC	717	13	8	10,000

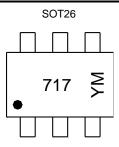
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



717 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Notes:

Duie Ooue	Rey												
Year	2015	2	016	2017	2018	2019	2020	202	1 20	22	2023	2024	2025
Code	С		D	E	F	G	Н			J	К	L	М
Mont	h	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	•	1	2	3	4	5	6	7	8	9	0	N	D

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### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-12	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-12	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Base Current	IB	-500	mA
Continuous Collector Current	Ι <sub>C</sub>	-3	A
Peak Pulse Collector Current	I <sub>CM</sub>	-10	A

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		1.1 8.8	W	
Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.7 13.6	mW/°C	
Thermal Desistance, Junction to Ambient	(Note 5)	P	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>θJA</sub>	73		
Thermal Resistance, Junction to Leads (Note 7)		R <sub>θJL</sub>	30.0	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

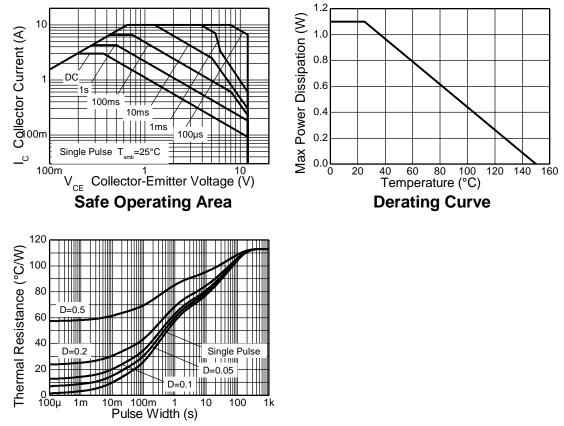
Notes: 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is measured at t  $\leq$  5 seconds.

Thermal resistance from junction to solder-point (at the end of the collector leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# Thermal Characteristics and Derating Information



**Transient Thermal Impedance** 





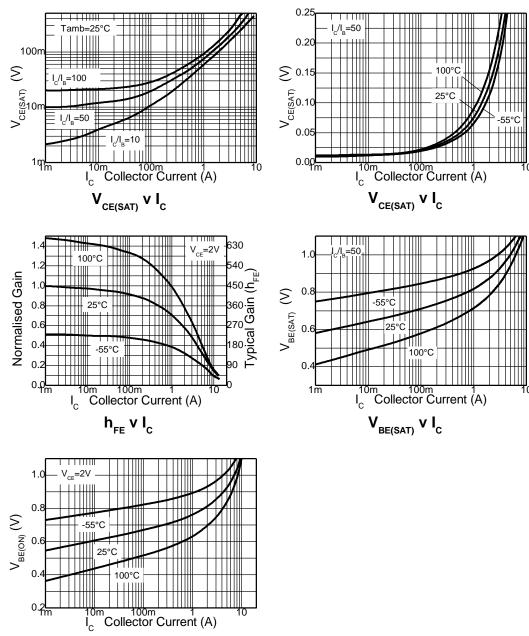
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Turn	Мах	Unit	Test Condition
OFF CHARACTERISTICS	Symbol	Min	Тур	wax	Unit	Test Condition
		10		[		
Collector-Base Breakdown Voltage	ВV <sub>CBO</sub>	-12	-35	_	V	I <sub>C</sub> = -100μΑ
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-12	-25	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.5	_	V	$I_E = -100\mu A$
Collector-Base Cutoff Current	I <sub>CBO</sub>		<1	-100	nA	V <sub>CB</sub> = -10V
Emitter Cutoff Current	I <sub>EBO</sub>		<1	-100	nA	$V_{EB} = -4V$
Collector-Emitter Cutoff Current	I <sub>CES</sub>		<1	-100	nA	$V_{CES} = -10V$
ON CHARACTERISTICS (Note 9)						
		300	475	_		$I_{C} = -10mA, V_{CE} = -2V$
		300	450		_	$I_{C} = -0.1A, V_{CE} = -2V$
DC Current Gain (Note 9)	h <sub>FE</sub>	180	275			$I_{C} = -2.5A, V_{CE} = -2V$
		60	100	_		$I_{C} = -8.0A, V_{CE} = -2V$
		45	70	_		$I_{C} = -10A, V_{CE} = -2V$
		_	-10	-17		$I_{C} = -0.1A, I_{B} = -10mA$
Collector-Emitter Saturation Voltage (Note 9)	Varia	_	-100	-140	mV	$I_{C} = -1.0A, I_{B} = -10mA$
	V <sub>CE(sat)</sub>		-100	-150	IIIV	$I_{C} = -1.5A, I_{B} = -50mA$
			-195	-300		$I_{C} = -3.0A, I_{B} = -50mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>		-0.90	-0.95	V	$I_{C} = -3.0A, I_{B} = -50mA$
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	_	-0.85	-0.90	V	$I_{C} = -3.0A, V_{CE} = -2V$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f <sub>T</sub>	80	110	_	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Output Capacitance	C <sub>obo</sub>	_	21	30	pF	V <sub>CB</sub> = -10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	_	70		ns	$V_{CC} = -6V, I_C = -2A$
Turn-Off Time	t <sub>(off)</sub>		130		ns	$I_{B1} = -I_{B2} = -50 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu s.$  Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

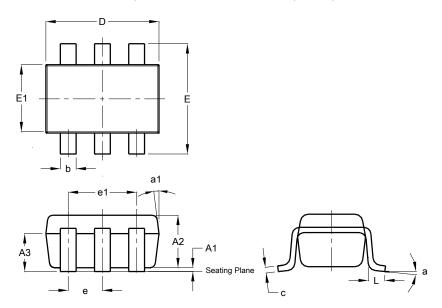


 $\mathbf{V}_{_{\mathsf{BE}(\mathsf{ON})}} ~\mathbf{v}~\mathbf{I}_{_{\mathsf{C}}}$ 



# **Package Outline Dimensions**

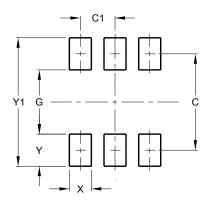
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26						
Dim	Min	Max	Тур				
A1	0.013	0.10	0.05				
A2	1.00	1.30	1.10				
A3	0.70	0.80	0.75				
b	0.35	0.50	0.38				
c	0.10	0.20	0.15				
D	2.90	3.10	3.00				
e	-	-	0.95				
e1	-	-	1.90				
Е	2.70	3.00	2.80				
E1	1.50	1.70	1.60				
L	0.35	0.55	0.40				
а	-	-	8°				
a1	-	-	7°				
All	Dimen	sions	in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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